Model 1522 Enhanced Performance Analog Surface Mount Accelerometer

• Low Noise: 7 ug/247 typical for 2g E	<u>Low Noise:</u> 7 μ g/ \sqrt{Hz} typical for 2g Full Scale Version			
Superior Bias & Scale Factor over Tem		1522013 622013	FULL SCALE ACCELERATION	20 PIN LCC
 <u>-55 to +125°C Operation</u> ±4V Differential Output +5 VDC, 5 mA Power (Typical) Responds to DC and AC Acceleration Integrated Sensor & Amplifier Internal Temperature Sensor Nitrogen Damped & Hermetically Sea Serialized for Traceability & RoHS Condition 		Positive Acceleration	± 2 g ± 5 g ± 10 g ± 25 g ± 50 g ± 100 g ± 200 g ± 400 g	1522L-002 1522L-005 1522L-010 1522L-025 1522L-050 1522L-100 1522L-200 1522L-200

DESCRIPTION

The Model 1522 is a low-cost, general-purpose integrated MEMS accelerometer with enhanced performance over temperature for use in zero to medium frequency applications experiencing large or rapid temperature variations or maintaining hot or cold extremes for extended periods of time. The Model 1522 accelerometers are individually tested, programmed, calibrated and verified in a climate chamber to ensure the greatest accuracy even in thermally volatile conditions.

Each miniature, hermetically sealed package combines a micro-machined capacitive sense element and a custom integrated circuit that includes a sense amplifier and differential output stage. Each device is marked with a serial number for traceability and come with an initial test report, which lists the measured bias, scale factor, bias and scale factor temperature coefficients, linearity, operating current and DV frequency response/phase plot.

ZERO (DC) TO MEDIUM FREQUENCY APPLICATIONS

SILICON DESIGNS INC Advanced Accelerometers



PERFORMANCE						
INPUT RANGE g	SENSITIVITY, DIFFERENTIAL mV/g	*FREQUENCY RESPONSE (TYPICAL, 5%) Hz	*FREQUENCY RESPONSE (TYPICAL, 3 DB) Hz	*FREQUENCY RESPONSE (MINIMUM, 3 DB) Hz	OUTPUT NOISE, DIFFERENTIAL (RMS, TYPICAL) µg/(root Hz)	MAX. MECHANICAL SHOCK (0.1 MS) g (peak)
±2	2000	0-250	0-525	0-300	7	
±5	800	0-400	0-800	0-420	12	2000
±10	400	0 – 700	0-1100	0 – 660	18	
±25	160	0-1300	0 - 1750	0 - 1050	25	-
±50	80	0-1600	0-2100	0-1400	50	5000
±100	40	0-1700	0-3000	0 - 1700	100	
±200	20	0 - 1900	0-3600	0-2100	200	
±400	10	0 – 2000	0-4200	0 - 2400	400	-

By Model: *V*_{*DD*}=*V*_{*R*}=5.0 *VDC*, *T*_{*C*}=25 ℃

***NOTE**: Frequency Response reported as performance once soldered. Simulating Frequency Response with the DV pin will report lower values than actual performance once soldered.

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PERFORMANCE - ALL VERSIONS

PARAMETER	MIN	ТҮР	MAX	UNITS	
Bias Calibration Error (mV)		20	50	± mV	
Bias Calibration Error (Span)		0.2	0.5	± % of span	
Bias Temperature Shift (Tc= -55 to +:	L25°C)	-50	0	+50	(PPM of span)/°C
Scale Factor Calibration Error ¹		0.5	1	± %	
Scale Factor Temperature Shift (Tc=	-100	0	+50	PPM/°C	
Non-Linearity (-90 to +90% of Full Scale) ¹			0.10	0.25	± % of span
Long Term Bias Stability			1000	2000	± PPM of span
Long Term Scale Factor Stability			500	1000	± PPM
Cross Axis Sensitivity			2	3	± %
Input Axis Misalignment			5	10	± mrad
Turn-On Transient (in less than 0.5ms)			75		± PPM of FS
Output Impedance			90		Ohms
Operating Voltage ²		4.75	5.0	5.25	volts
Operating Current (IDD+IVR)			5	6.5	mA
Mass: 'L' package			0.62		grams
Max Case Operating Temperature	-55 to +125°C	Voltage on V_{DD} to GND		-0.5V to 6.0V	
Max Storage Temperature	-55 to +125°C	Voltage on Any Pin (except DV) to GND ²		-0.5V to V _{DD} +0.5V	
Max Reflow Solder Temperature	+239°C	Voltage on DV to GND (Self-Test)			±15V
	Power Dissipation	35 mW			

Note 1: For 2g thru 50g only; 100g and greater versions are tested and specified from -65 to +65g.

Note 2: Voltages on pins other than DV, GND or V_{DD} may exceed 0.5 volt above or below the supply voltages provided the current is limited to 1 mA.

NOTICE: Minimize exposure above 125°C for maximum lifespan. Stresses greater than those listed above may cause permanent damage to the device. These are maximum stress ratings only. Functional operation of the device at or above these conditions is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability and lifespan.

BIAS & SCALE FACTOR TEMPERATURE SHIFT EXPLAINED

Bias is the accelerometer output with no acceleration present. For SDI's differential output analog accelerometers, it is a signed quantity that is expressed in terms of either g or output volts and is ideally equal to zero g or zero volts.

Bias Temperature Shift (Coefficient) is the amount of bias shift to expect with a change in temperature expressed as PPM of span per °C. For example, the percent of span bias shift that would occur for a 25g full scale device with a +/-200 PPM of span per °C rating and a 55 °C rise from room temperature would be: +/-200 / 1,000,000 x (80C - 25C) x 100% of span = +/- 1.1% of span. The g shift would be +/-1.1% of 50g = 0.55 g. This error in terms of output voltage for a 25 g analog accelerometer would be +/-1.1% of span = +/- 1.1% of 8 V = 88 mV.

Scale Factor is the ratio of the change in output to a unit change in the input acceleration expressed in millivolts per g (mV/g). Since the output of most accelerometers is slightly non-linear, the scale factor value is defined as the slope of the least-squares-fit line to the acceleration input vs output curve. SDI measures over the range of -90% to +90% of full scale or from -65g to +65g, whichever is smaller.

Scale Factor Temperature Shift (Coefficient) is the amount of scale factor shift to expect with a change in temperature expressed as PPM per °C. For example, the percent shift in scale factor that would occur for a device with a +200 PPM per °C rating and a 60 °C rise from room temperature would be: $+200 / 1,000,000 \times (85C - 25C) \times 100\% = +1.2\%$. For an analog 10g device, the scale factor would rise from its nominal (8 V)/(20 g) = 400 mV/g at +25C to 400 mV/g +1.2% = 404.8 mV/g.

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SAMPLE OF INCLUDED TEST REPORT

Every 1522 accelerometer is accompanied by a test report featuring the measured bias, scale factor, bias and scale factor over temperature, linearity, output, and frequency and phase response.



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OPERATION

The model 1522 sensitive axis is perpendicular to the bottom of the package, with positive acceleration resulting from a positive force pushing on the bottom of the package. The seismic center is located on a centerline through the dual sense elements and halfway between them. The internal electronics effectively cancel any errors due to rotation. Two reference voltages, +5.0 and +2.5 volts (nominal), are required; scale factor is ratiometric to the +5.0-volt reference voltage relative to GND.

The Model 1522 produces a differential +/-4 volts output at full scale, the value of which varies with acceleration as shown in the graphic below.



SIGNAL DESCRIPTIONS

- V_{DD} and GND (power): Pins (14) and (19) respectively. Power (+5 Volts DC) and ground.
- **AOP and AON (output):** Pins 12 and 16 respectively. Analog output voltages proportional to acceleration. The AOP voltage increases (AON decreases) with positive acceleration; at zero acceleration both outputs are nominally equal to the +2.5 volt reference. The device experiences positive (+1g) acceleration with its lid facing up in the earth's gravitational field. Use of differential mode is strongly recommended for both lowest noise and highest accuracy operation. Voltages can be measured ratio-metrically to VR for good repeatability without requiring a separate precision reference voltage for an A/D.



DV (input): Pin 4. Deflection Voltage. A test input that applies an electrostatic force to the sense element, simulating a positive acceleration. The nominal voltage at

this pin is ½ V_{DD}. DV voltages higher than required to bring the output to positive full scale may cause device damage.

- VR (input): Pin 3. Voltage Reference. Tie to a good reference (not directly to VDD) for best scale factor repeatability. A 0.1µF bypass capacitor is recommended at this pin. VR current is less than 100 uA.
- **2.5 Volt (input):** Pin 17. Sets internal and output common mode value. Tie to a resistive voltage divider from +5 volts. A 0.1μF bypass capacitor is recommended at this pin.
- IT (output): Pin 8. Temperature dependent current source. May be tied to VDD or left disconnected if not used.

Special Use Pins: Pins 9 and 11 should be tied to VDD, Pins 2, 5, 6, and 18 to GND.

** Pins 1, 7, 10, 13, 15, and 20 are reserved for future use and should remain unused **

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OPTIONAL INTERNAL TEMPERATURE SENSING

The model 1522 accelerometer contains a temperature dependent current source that is output on pin 8. This signal is useful for measuring the internal temperature of the accelerometer so that any previously characterized bias and scale factor temperature dependence, for a particular accelerometer, can be corrected.



 $\frac{\Delta V_T}{\Lambda T} = R_T (1.5 \mu A)$

The nominal output current at 25°C is \approx 500 (±200) μ A and the nominal sensitivity is 1.5 (±0.5) μ A/°C. Fluctuations in V_{DD} & V_R have little effect on the temperature reading. A reduction of 0.10 V to both V_{DD} & V_R will reduce the current about 1 μ A, which corresponds to less than a 1°C change in reading. With a single resistor R_T = 2K between I_T (pin 8) and GND the output voltage V_T will vary between +0.76 and +1.3 volts from -55 to +125°C, which equates to a sensitivity of \approx +3 mV/°C.

$$V_T \approx R_T [(500 \,\mu A) + [(1.5 \,\mu A)(T - 25)]]$$



a greater voltage change versus temperature or lower signal source
pedance is needed, add the amplifier as shown on the right side in Figure
With offset voltage
$$V_{OFF} = -5V$$
, gain resistor $R_G = 15.0K$ and offset resistor
 $r_F = 7.32K$, the output voltage V_T will vary between +4.5 and +0.5 Volts
m -55 to +125°C, which equates to a sensitivity of \approx -29 mV/°C.

$$V_{T} \approx -R_{G} \left[\frac{V_{OFF}}{R_{OFF}} + (500\,\mu A) + \left[(1.5\,\mu A)(T-25) \right] \right] R_{G} = \frac{-\Delta V_{T}}{(1.5\,\mu A)(\Delta T)}$$
$$R_{OFF} = \frac{-V_{OFF}}{\left(\frac{V_{T}}{R_{G}} \right) + (500\,\mu A) + \left[(1.5\,\mu A)(T-25) \right]} \frac{\Delta V}{\Delta T} = -R_{G}(1.5\,\mu A)$$

Figure 3 shows the voltage compliance of the temperature dependent current source (I_T) at room temperature. The voltage at pin 8 must be kept in the 0 to +3V range in order to achieve proper temperature readings.

PACKAGE DIMENSIONS

- 1. *Dimensions "M," "T," and "U" locate sensing element's center of mass.
- 2. Lid is electrically tied to terminal 19 (GND).
- 3. Controlling dimension: Inch.
- 4. Terminals are plated with 60 microinches min gold over 80 microinches min nickel. This plating specification does not apply to the Pin-1 identifier mark on the bottom of the J-lead package version.
- 5. Package: 90% min alumina (black), lid: solder sealed kovar.



*M

D.

	Inches		Millimeters		
Dim	Min	Max	Min	Max	
Α	0.342	0.358	8.69	9.09	
С	0.055 TYP		1.40 TYP		
D	0.095	0.115	2.41	2.92	
E	0.085 TYP		2.16 TYP		
F	0.050 BSC		1.27 BSC		
G	0.025 TYP		0.64 TYP		
Н	0.050 TYP		1.27 TYP		
J	0.004 x 45°		0.10 x 45°		
К	0.010 R TYP		0.25 R TYP		
L	0.016 TYP		0.41 TYP		
*M	0.066 TYP		1.68 TYP		
*T	0.085 TYP		2.16 TYP		
*U	0.175 TYP		4.45 TYP		

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RECOMMENDED CONNECTIONS

DEFLECTION VOLTAGE (DV) TEST INPUT: This test input applies an electrostatic force to the sense element, simulating a positive acceleration. It has a nominal input impedance of 32 k Ω and a nominal open circuit voltage of ½ V_{DD}. For best accuracy during normal operation, this input should be left unconnected or connected to a voltage source equal to ½ of the V_{DD} supply. The change in differential output voltage (AOP - AON) is proportional to the square of the difference between the voltage applied to the



DV input (**V**_{DV}) and ½ **V**_{DD}. Only positive shifts in the output voltage may be generated by applying voltage to the **DV** input. When voltage is applied to the **DV** input, it should be applied gradually. The application of **DV** voltages greater than required to bring the output to positive full scale may cause device damage. The proportionality constant (**k**) varies for each device and is not characterized.

ESD and LATCH-UP CONSIDERATIONS: The model 1522 accelerometer is a CMOS device subject to damage from large electrostatic discharges. Diode protection is provided on the inputs and outputs, and it is not easily damaged, but care should be exercised during handling. However, individuals and tools should be grounded before coming in contact with the device. Although the 1522 is resistant to latch-up, inserting a 1522 into or removing it from a powered socket may cause damage.

SOLDERING RECOMMENDATIONS

Recommended Solder Pad Pattern: The recommended solder pad size and shape for the LCC package is shown in the diagram and table. These dimensions are recommendations only and may or may not be optimum for your particular soldering process.

RoHS Compliance: The model 1522 does not contain elemental lead and is RoHS compliant.

Soldering: Solder reflow should not exceed 239°C, exceeding this temperature may result in permanent damage.

Pre-Tinning of Accelerometer Leads is Recommended: To prevent gold migration embrittlement of the solder joints, it is best to pre-tin the accelerometer leads.

LCC Solder Contact Plating Information: The plating composition and thickness for the solder pads and castellations on the "L" suffix (LCC) package are 60 to 225 micro-inches thick of gold (Au) over 80 to 350 micro-inches thick of nickel (Ni) over a minimum of 5 micro-inches thick of molymanganese or tungsten refractory material.

Do not use ultrasonic cleaners. Ultrasonic cleaning may break internal wire bonds and will void the warranty.



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